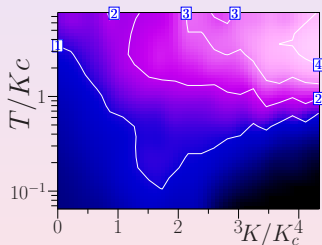
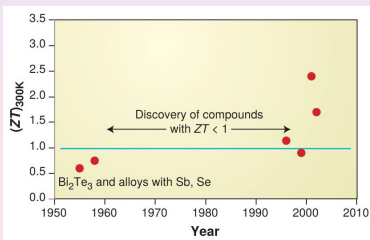
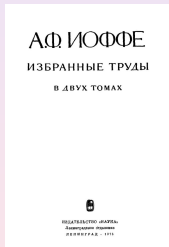


Thermoelectricity at nanoscale: theoretical models



Dima Shepelyansky (CNRS, Toulouse)
www.quantware.ups-tlse.fr/dima

Joint work with Oleg Zhironov (BINP) Europhys. Lett. **103**, 68008 (2013)



Time evolution of figure of merit ZT (center)
(from A.Majumdar Science **303**, 777 (2004))

Early works



T. Seebeck-deflection of a compass
needle (circa 1823)

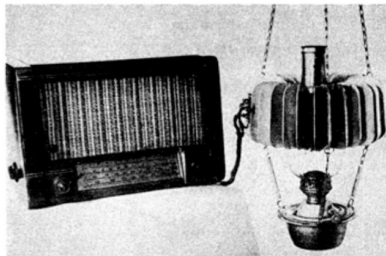
from Y.Imry (Weizmann Inst) talk at Inst. H. Poincaré, Paris (2012)

Early works



A. F. Ioffe

semiconductors
and figure of merit



Oil burning lamp powering a radio using
the first commercial thermoelectric
generator containing ZnSb built in
USSR, circa 1948

from Y.Imry (Weizmann Inst) talk at Inst. H. Poincaré, Paris (2012)

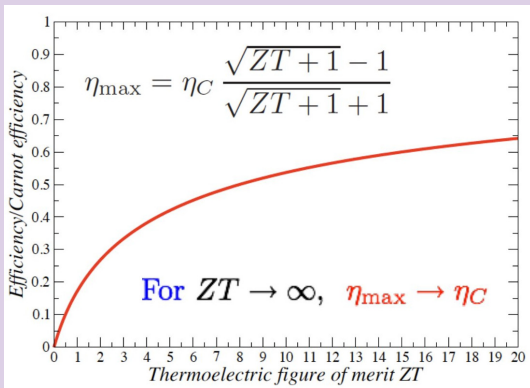
Main characteristics

Seebeck coefficient:

$$S = \Delta V / \Delta T = \pi^2 k_B^2 T [(d \ln \sigma / dE)]|_{E_F} / e \text{ (Mott relation (1958))}$$

For 2DEG with Wiedemann-Franz law: $S = 2\pi k_B^2 T m / (3eh^2 n_e)$;

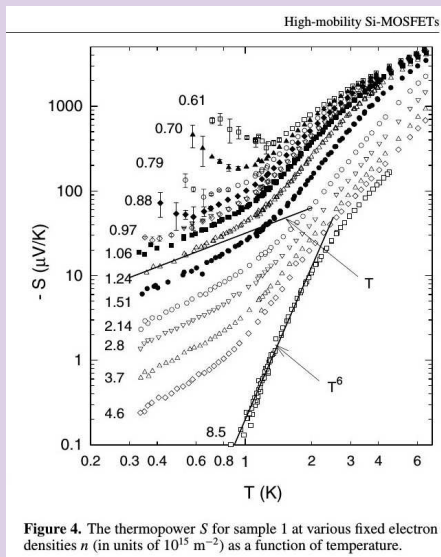
typical value $S \approx 10 \mu\text{V}/\text{K}$ at $T = 0.3\text{K}$, $n_e = 4 \cdot 10^{10} \text{cm}^{-2}$



Thermoelectric figure of merit $ZT = \sigma S^2 T / \kappa$,

thermal conductivity $\kappa = \kappa_{el} + \kappa_{phonon}$ (heat flux $Q = -\kappa \nabla T$)

Experiments on Seebeck coefficient for 2DEG



R.Fletcher, V.M.Pudalov et al. *Semicond. Sci. Technol.* **15**, 386 (2001)

Experiments on Seebeck coefficient for 2DEG

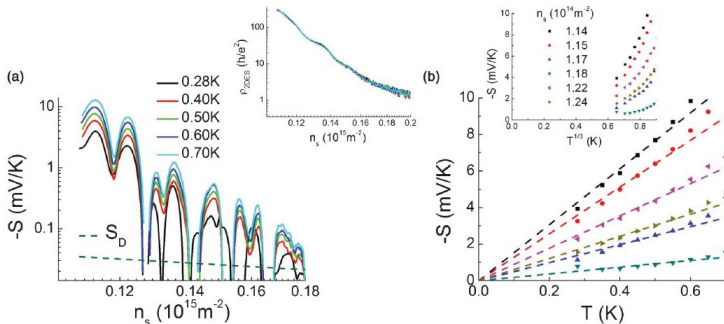
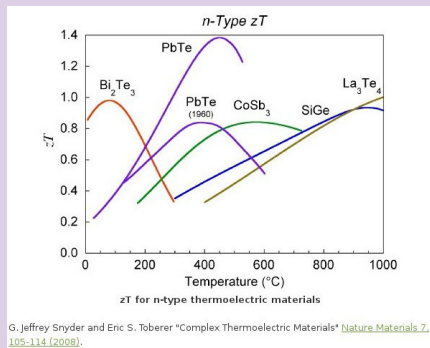
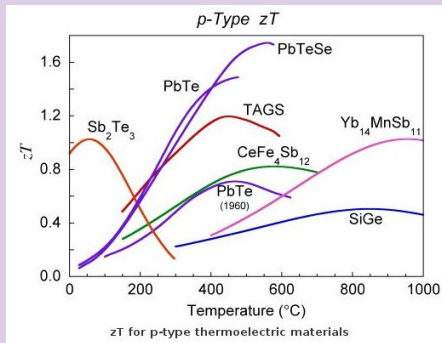


FIG. 5. (Color online) (a) S vs n_s for $0.28 \text{ K} < T < 0.7 \text{ K}$. The broken green line shows S_D [Eq. (2)] at 0.28 K . Inset: ρ_{2DES} vs n_s at the same T values; there is little T dependence in this range. (b) Low- T linear variation of S . Inset: Descriptions based on variable-ranged hopping, where S is expected to decay to zero as $T^{1/3}$, do not adequately describe the observed data.

V.Narayan, S.Goswami, M.Pepper et al. PRB **85**, 125406 (2012)

In dimensionless units $S = 10 \text{ mV/K} \approx 100 \gg 1$

ZT in various materials



from <http://www.thermoelectrics.caltech.edu/thermoelectrics/>

ZT in p-type $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ superlattices

Phonon-blocking/electron-transmitting structures

The results obtained with the $10\text{\AA}/50\text{\AA}$ $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ superlattices indicate that we can fine-tune the phonon and hole (charge carriers)

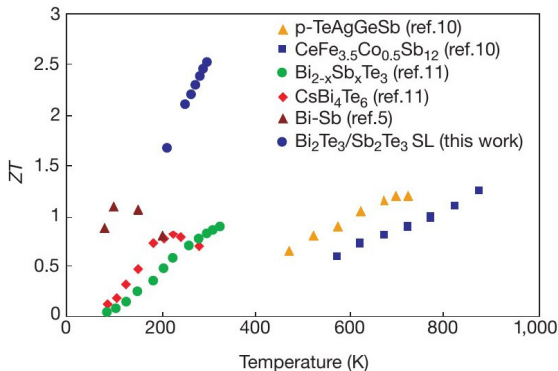


Figure 3 Temperature dependence of ZT of $10\text{\AA}/50\text{\AA}$ p-type $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ superlattice compared to those of several recently reported materials.

R.Venkatasubramanian et al. (N.Carolina) Nature **413**, 597 (2001)

ZT in SnSe

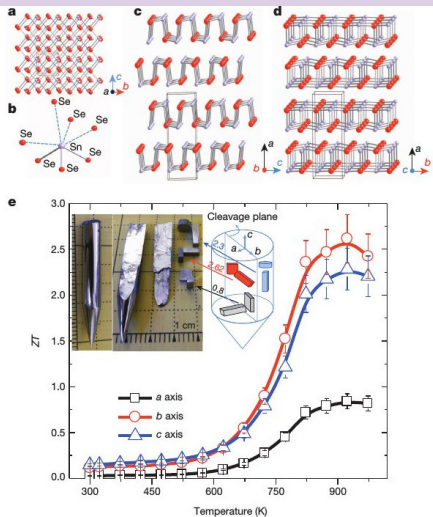
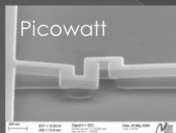


Figure 1 | SnSe crystal structure *Pnma* and ZT values. **a**, Crystal structure along the *a* axis: grey, Sn atoms; red, Se atoms. **b**, Highly distorted SnSe₇ coordination polyhedron with three short and four long Sn–Se bonds. **c**, Structure along the *b* axis. **d**, Structure along the *c* axis. **e**, Main panel, ZT values along different axial directions; the ZT measurement uncertainty is about 15% (error bars). Inset images: left, a typical crystal; right, a crystal cleaved along the (100) plane, and specimens cut along the three axes and corresponding measurement directions. Inset diagram, how crystals were cut for directional measurements; ZT values are shown on the blue, red and grey arrows; colours represent specimens oriented in different directions.

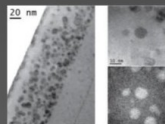
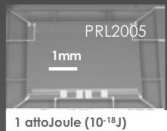
Li-Dong Zhao et al. (Illinois) Nature **508**, 373 (2014)

Research at CNRS Grenoble (O.Bourgeois Refs.3,4)

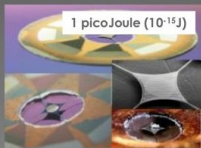
Heat exchange at the nanoscale: from low temperature to room temperature



NanoLett 2009, PRB 2010

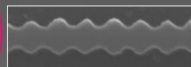


Thermoelectrics in GeMn

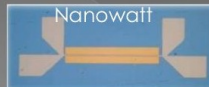


Rev. Sci. Instrum. **81**, 053901 (2010)

Heat
Transport at
the
nanoscale



Phononic crystal



A. Sikora, H. Ftouni, J. Richard, and O.B.,
Rev. Sci. Instrum. **83**, 054902 (2012).

Applications

TE Applications are mostly 'Niche' Applications

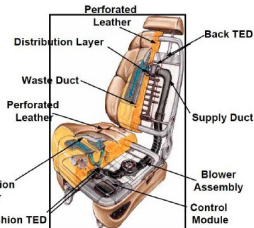
-Laser, PCR



CITIZEN
Eco-Drive Thermo
Watch



Production CCS
Assembly



today...

POWER SOURCE

- Batteries

CLIMATE CONTROL

- None



Enabled by
Thermoelectrics (TE)

...tomorrow

POWER SOURCE

- Logistic fuel based system

CLIMATE CONTROL

- Thermoelectric based cooling/heating
- On-demand

IMPACT

- >30% weight savings over existing systems

Assumptions

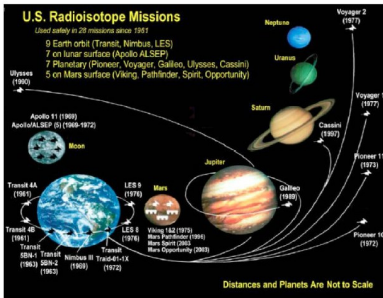
12 hour mission @ 110°F ambient temperature

DARPA TTO Program Manager: Ed van Reuth

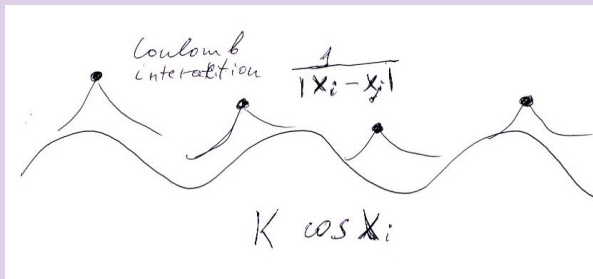
U.S. Radioisotope Missions

Used safely in 28 missions since 1961

- 9 Earth orbit (Transit, Nimbus, LES)
- 7 on lunar surface (Apollo ALSEP)
- 7 Planetary (Pioneer, Voyager, Galileo, Ulysses, Cassini)
- 5 on Mars surface (Viking, Pathfinder, Spirit, Opportunity)



Thermoelectricity of Wigner crystal in a periodic potential



$$\text{Hamiltonian } H = \sum_i \left(\frac{p_i^2}{2} + K \cos x_i + \frac{1}{2} \sum_{j \neq i} \frac{1}{|x_i - x_j|} \right)$$

Dynamic equations $\dot{p}_i = -\partial H / \partial x_i + E_{dc} - \eta p_i + g \xi_i(t)$, $\dot{x}_i = p_i$

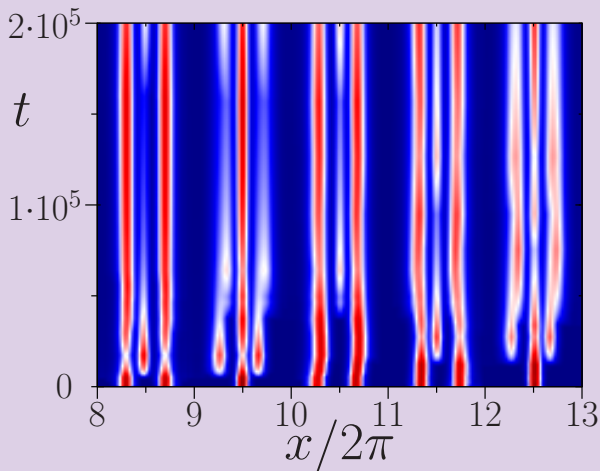
Here the Langevin force is given by $g = \sqrt{2\eta T}$, $\langle \xi_i(t) \xi_j(t') \rangle = \delta_{ij} \delta(t - t')$;

$n_e = \nu / 2\pi$, $\nu = \nu_g = 1.618\dots$ Fibonacci rational approximates.

Aubry transition at $K = K_c = 0.0462$.

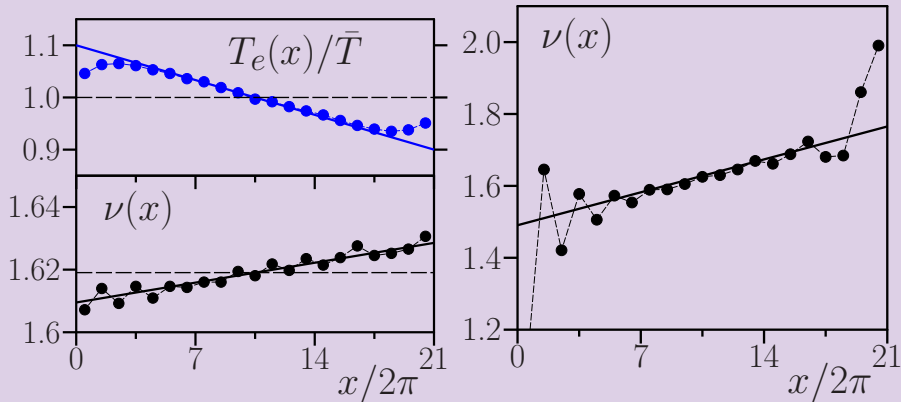
I.Garcia-Mata, O.Zhiron, DLS EPJD **41, 325 (2007)**

Time evolution of Wigner crystal



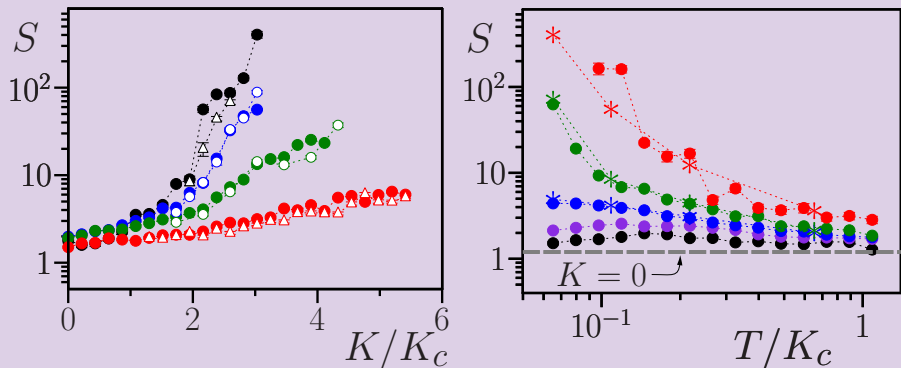
Electron density variation in space and time from one Langevin trajectory at $K/K_c = 2.6$, $T/K_c = 0.11$, $\eta = 0.02$, $N = 34$, $M = L/2\pi = 21$; density changes from zero (dark blue) to maximal density (dark red); only a fragment of x space is shown.

Numerical fits



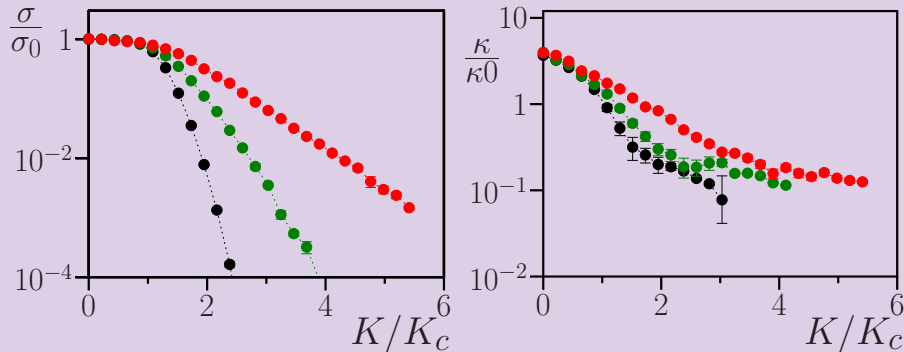
Left panels: dependence of electron temperature $T_e(x)$ (top, blue points) and rescaled density $\nu(x)$ (bottom, black points) on distance x along the chain placed on the Langevin substrate with a constant temperature gradient (it is shown by the blue line) at average temperature $\bar{T} = 0.01$ and temperature difference $\Delta T = 0.2\bar{T}$; black line shows the fit of density variation in the bulk part of the sample. Right panel: density variation produced by a static electric field $E_{dc} = 4 \times 10^{-4}$ at a constant substrate temperature $T = 0.01$; black line shows the fit of gradient in the bulk part of the sample. Here $N = 34$, $M = 21$, $K = 1.52K_C$, $\eta = 0.02$, averaging is done over time interval $t = 10^7$; $S = 3.3$ at $T = 0.01 \approx 0.22K_C$.

Seebeck coefficient



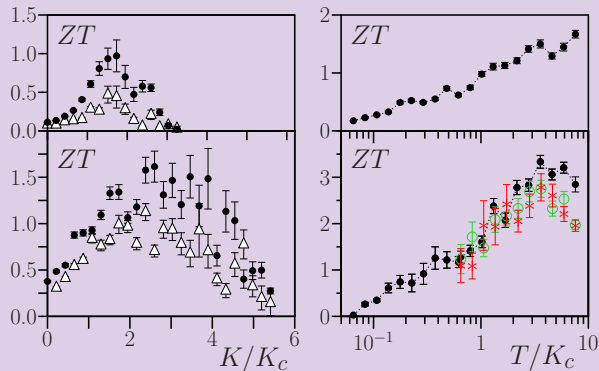
Left panel: Dependence of the Seebeck coefficient S on rescaled potential amplitude K/K_c at temperatures $T/K_c = 0.065, 0.11, 0.22$ and 0.65 shown by black, blue, green and red colors, respectively from top to bottom. The full and open symbols correspond respectively to chains with $N = 34, M = 21$ and $N = 55, M = 34$. *Right panel:* Dependence of S on T/K_c at different $K/K_c = 0, 0.75, 1.5, 2.2, 3$ shown respectively by black, violet, blue, green and red points; $N = 34, M = 21$; the dashed gray line shows the case $K = 0$ for noninteracting particles. The stars show corresponding results from left plane at same N, M . Dotted curves are drawn to adapt an eye. Here and in other Figs. the statistical error bars are shown when they are larger than the symbol size. Here $\tau_j = 0.02$.

Conductivity and thermal conductivity



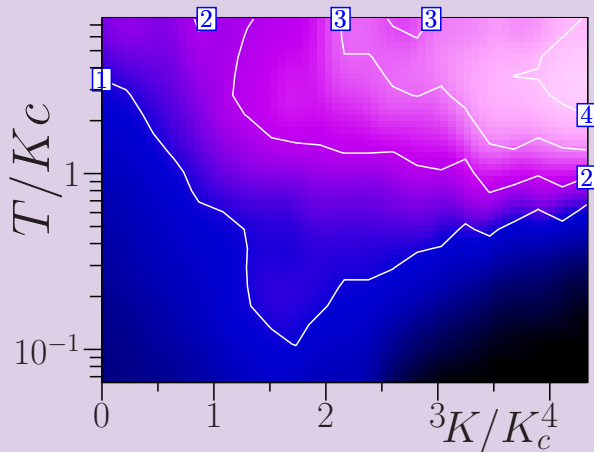
Left panel: Rescaled electron conductivity σ/σ_0 as a function of K/K_c shown at rescaled temperatures $T/K_c = 0.065, 0.22, 0.65$ by black, green and red points respectively. *Right panel:* Rescaled thermal conductivity κ/κ_0 as a function of K/K_c shown at same temperatures and colors as in left panel. Here we have $N = 34, M = 21, \eta = 0.02, \sigma_0 = \nu_g/(2\pi\eta), \kappa_0 = \sigma_0 K_c$.

ZT dependence on parameters



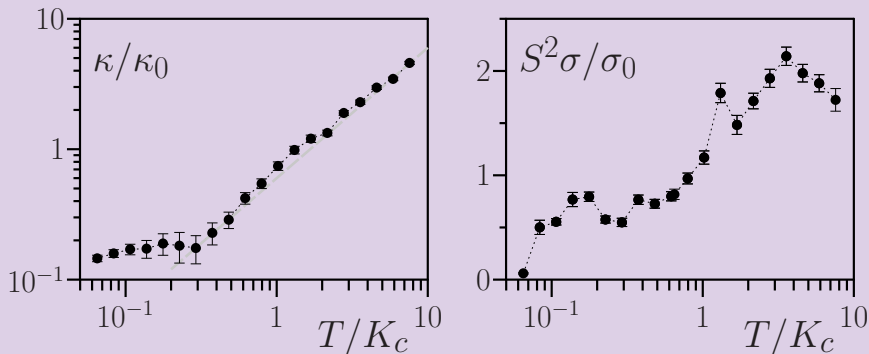
Left panels: Dependence of ZT on K/K_c at temperatures $T/K_c = 0.11$ (top panel) and $T/K_c = 0.65$ (bottom panel); the black points and open triangles correspond respectively to $\eta = 0.02$ and $\eta = 0.05$ at $N = 34$, $M = 21$. *Right panels:* Dependence of ZT on T/K_c for $K/K_c = 0.75$ at $\eta = 0.02$, $N = 34$, $M = 21$. *Bottom right panel:* Same as in top right panel at $K/K_c = 2.6$ and $N = 34$, $M = 21$ (black points); $N = 89$, $M = 55$ (green circles); $N = 144$, $M = 89$ (red stars).

ZT dependence on parameters



Dependence of ZT on K/K_c and T/K_c shown by color changing from $ZT = 0$ (black) to maximal $ZT = 4.5$ (light rose); contour curves show values $ZT = 1, 2, 3, 4$. Here $\eta = 0.02$, $N = 34$, $M = 21$.

Other quantities dependences



Left panel: Rescaled thermal conductivity κ/κ_0 as a function of rescaled temperature T/K_c , to adapt an eye the straight dashed line shows the dependence $\kappa/\kappa_0 = 0.6T/K_c$; *right panel:* same as in left panel for $S^2\sigma/\sigma_0$. Data are obtained at $K/K_c = 2.6$, $\eta = 0.02$, $N = 34$, $M = 21$, $\sigma_0 = \nu_g/(2\pi\eta)$, $\kappa_0 = \sigma_0 K_c$.

Physical parameters

In physical units we can estimate the critical potential amplitude as $U_c = K_c e^2 / (\epsilon d)$, where ϵ is a dielectric constant, Δx is a lattice period and $d = \nu \Delta x / 2\pi$ is a rescaled lattice constant Ref.5. For values typical for a charge density wave regime Ref.6 we have $\epsilon \sim 10$, $\nu \sim 1$, $\Delta x \sim 1 \text{ nm}$ and $U_c \sim 40 \text{ mV} \sim 500 \text{ K}$ so that the Aubry pinned phase should be visible at room temperature. The obtained U_c value is rather high that justifies the fact that we investigated thermoelectricity in the frame of classical mechanics of interacting electrons.

Message from Novosibirsk GES



References:

- R1. A.F.Ioffe and L.S.Syil'bans, Re. Prog. Phys. **22**, 167 (1969)
- R2. H.J. Goldsmid, *Introduction to thermoelectricity*, Springer, Berlin (2009).
- R3. Nanoelectronics : Concepts, Theory and Modeling. Network meeting and workshop on thermoelectric transport 21-27 October 2012, Cargese, Corsica <http://iramis.cea.fr/meetings/nanoctm/program.php>
- R4. Slides at R3 by O.Bourgeois, L.W.Molenkamp, S.Voltz
- R5. I.Garcia-Mata, O.V.Zhirov, D.L.Shepelyansky, EPJD **41**, 325 (2007)
- R6. S.Brazovskii *et al.*, Phys. Rev. Lett. **108**, 096801 (2012)